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74LVX161284 Low Voltage IEEE 161284 Translating Transceiver

General Description

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The LVX161284 contains eight bidirectional data buffers and eleven control/status buffers to implement a full IEEE 1284 compliant interface. The device supports the IEEE 1284 standard and is intended to be used in an Extended Capabilities Port mode (ECP). The pinout allows for easy connection from the Peripheral (A-side) to the Host (cable side).

Outputs on the cable side can be configured to be either open drain or high drive (\pm 14 mA) and are connected to a separate power supply pin (V_{CC}-cable) to allow these outputs to be driven by a higher supply voltage than the A-side. The pull-up and pull-down series termination resistance of these outputs on the cable side is optimized to drive an external cable. In addition, all inputs (except HLH) and outputs on the cable side contain internal pull-up resistors connected to the V_{CC}-cable supply to provide proper termination and pull-ups for open drain mode.

Outputs on the Peripheral side are standard low-drive CMOS outputs designed to interface with 3V logic. The DIR input controls data flow on the A_1-A_8/B_1-B_8 transceiver pins.

Features

- Supports IEEE 1284 Level 1 and Level 2 signaling standards for bidirectional parallel communications between personal computers and printing peripherals
- Translation capability allows outputs on the cable side to interface with 5V signals
- All inputs have hysteresis to provide noise margin
- B and Y output resistance optimized to drive external cable
- B and Y outputs in high impedance mode during power down
- Inputs and outputs on cable side have internal pull-up resistors
- Flow-through pin configuration allows easy interface between the "Peripheral and Host"
- Replaces the function of two (2) 74ACT1284 devices

Ordering Code

Order Number	Package Number	Package Description
74LVX161284MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVX161284MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code

Connection Diagram DIR HD 48 Α9 Yg Y₁₀ A₁₀ 46 A11 - A12 -45 44 Y₁₁ $\begin{array}{c} & \stackrel{\tau_{12}}{\underset{\scriptstyle \downarrow}{\overset{\scriptstyle }}} \\ & \stackrel{\tau_{13}}{\underset{\scriptstyle \downarrow}{\overset{\scriptstyle }}} \\ & \stackrel{V_{CC..cable}}{\underset{\scriptstyle B_1}{\overset{\scriptstyle }}} \\ & \stackrel{B_2}{\underset{\scriptstyle GND}{\overset{\scriptstyle }}} \\ \\ & \stackrel{g_{\eta}}{\underset{\scriptstyle }} \end{array}$ Y1 2 43 42 A13 V_{CC} A1 A2 41 40 GND 39 ---- 83 --- 84 38 37 A3 A4 A5 A6 11 12 13 14 B5 B6 GND B7 36 35 GND A7 A8 15 16 17 18 19 34 33 32 31 30 Β, cable V_{CC} PLH C14 C15 C16 C17 PLHin 20 21 29 28 A₁₄ A₁₅ A16 A17 22 27 23 26 HLE 24 25 HLHin

Pin Descriptions

Pin Names	Description				
HD	High Drive Enable Input (Active HIGH)				
DIR	Direction Control Input				
A ₁ –A ₈	Inputs or Outputs				
В ₁ –В ₈	Inputs or Outputs				
A ₉ –A ₁₃	Inputs				
Y ₉ –Y ₁₃	Outputs				
A ₁₄ –A ₁₇	Outputs				
C ₁₄ –C ₁₇	Inputs				
PLH _{IN}	Peripheral Logic HIGH Input				
PLH	Peripheral Logic HIGH Output				
HLH _{IN}	Host Logic HIGH Input				
HLH	Host Logic HIGH Output				
	•				



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Absolute Maximum Rati	ngs(Note 3)	Recommended Operating			
Supply Voltage		Conditions			
V _{cc}	-0.5V to +4.6V	Supply Voltage			
V _{CC—Cable}	-0.5V to +7.0V	V _{CC}	3.0V to 3.6V		
$V_{CC-Cable}$ Must Be $\geq V_{CC}$		V _{CC} —Cable	3.0V to 5.5V		
Input Voltage (VI)—(Note 4)		DC Input Voltage (V ₁)	0V to V _{CC}		
A ₁ –A ₁₃ , PLH _{IN} , DIR, HD	-0.5V to V _{CC} + 0.5V	Open Drain Voltage (V _O)	0V to 5.5V		
B ₁ –B ₈ , C ₁₄ –C ₁₇ , HLH _{IN}	-0.5V to +5.5V (DC)	Operating Temperature (T_{Δ})	–40°C to +85°C		
B ₁ –B ₈ , C ₁₄ –C ₁₇ , HLH _{IN}	-2.0V to +7.0V*				
	*40 ns Transient				
Output Voltage (V _O)					
A ₁ -A ₈ , A ₁₄ -A ₁₇ , HLH	-0.5V to V _{CC} +0.5V				
B ₁ –B ₈ , Y ₉ –Y ₁₃ , PLH	-0.5V to +5.5V (DC)				
B ₁ –B ₈ , Y ₉ –Y ₁₃ , PLH	-2.0V to +7.0V*				
	*40 ns Transient				
DC Output Current (I _O)					
A ₁ –A ₈ , HLH	±25 mA				
B ₁ –B ₈ , Y ₉ –Y ₁₃	±50 mA				
PLH (Output LOW)	84 mA				
PLH (Output HIGH)	–50 mA				
Input Diode Current (I _{IK})—(Note 4) DIR, HD, A_9 – A_{13} , PLH, HLH, C_{14} – C_{17}	–20 mA				
Output Diode Current (I _{OK})					
A ₁ -A ₈ , A ₁₄ -A ₁₇ , HLH	±50 mA				
B ₁ –B ₈ , Y ₉ –Y ₁₃ , PLH	–50 mA	Note 3: Absolute maximum ratings are values beyond	d which the device		
DC Continuous V _{CC} or Ground		may be damaged or have its useful life impaired. Fairch			
Current	±200 mA	mend operation outside the databook specifications.	protoct inputs		
Storage Temperature	-65°C to +150°C	Note 4: Either voltage limit or current limit is sufficient to	protect inputs.		
ESD (HBM) Last Passing Voltage	2000V				

DC Electrical Characteristics

			.,		$\mathbf{T}_{\mathbf{A}} = 0^{\circ}\mathbf{C}$	$T_A = -40^{\circ}C$		
Symbol	Parameter		V _{CC} (V)	V _{CC—Cable} (V)	to +70°C	to +85°C	Units	Conditions
		(-)	(-)	Guaranteed Limits				
V _{IK}	Input Clamp		3.0	3.0	-1.2	-1.2	V	I _i = -18 mA
	Diode Voltage							
VIH	Minimum	A _n , B _n , PLH _{IN} , DIR, HD	3.0-3.6	3.0-5.5	2.0	2.0		
	HIGH Level	C _n	3.0-3.6	3.0-5.5	2.3	2.3	V	
	Input Voltage	HLH _{IN}	3.0-3.6	3.0-5.5	2.6	2.6		
VIL	Maximum	A _n , B _n , PLH _{IN} , DIR, HD	3.0-3.6	3.0-5.5	0.8	0.8		
	LOW Level	C _n	3.0-3.6	3.0-5.5	0.8	0.8	V	
	Input Voltage	HLH _{IN}	3.0-3.6	3.0-5.5	1.6	1.6		
ΔV_T	Minimum Input	A _n , B _n , PLH _{IN} , DIR, HD	3.3	5.0	0.4	0.4		V _T ⁺ –V _T
	Hysteresis	C _n	3.3	5.0	0.8	0.8	V	$V_T^+ - V_T^-$
		HLH _{IN}	3.3	5.0	0.2	0.2		$V_{T}^{+} - V_{T}^{-}$
V _{ОН}	Minimum HIGH	A _n , HLH	3.0	3.0	2.8	2.8		I _{OH} = -50 μA
	Level Output		3.0	3.0	2.4	2.4		$I_{OH} = -4 \text{ mA}$
	Voltage	B _n , Y _n	3.0	3.0	2.0	2.0	V	$I_{OH} = -14 \text{ mA}$
		B _n , Y _n	3.0	4.5	2.23	2.23		$I_{OH} = -14 \text{ mA}$
		PLH	3.15	3.15	3.1	3.1	1	$I_{OH} = -500 \ \mu A$

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R _D	Pa Maximum LOW Level Output Voltage Maximum Output Impedance Minimum Output Impedance Maximum Pull-Up Resistance	A _n , HLH B _n , Y _n B _n , Y _n PLH PLH B ₁ -B ₈ , Y ₉ -Y ₁₃ B ₁ -B ₈ , Y ₉ -Y ₁₃	V _{CC} (V) 3.0 3.0 3.0 3.0 3.0 3.0 3.0 3.0 3.0 3.0 3.3 3.3 3.3	V _{CC-Cable} (V) 3.0 3.0 4.5 3.0 4.5 3.0 4.5 3.3 5.0	T _A = 0°C to +70°C Guarantu 0.2 0.4 0.8 0.77 0.85 0.8 60 55	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	Vnits	$I_{OL} = 4 \text{ mA}$ $I_{OL} = 14 \text{ m/}$ $I_{OL} = 14 \text{ m/}$ $I_{OL} = 84 \text{ m/}$
R _D	Level Output Voltage Maximum Output Impedance Minimum Output Impedance Maximum Pull-Up	B _n , Y _n B _n , Y _n PLH PLH B ₁ -B ₈ , Y ₉ -Y ₁₃ B ₁ -B ₈ , Y ₉ -Y ₁₃	3.0 3.0 3.0 3.0 3.0 3.0 3.0 3.0 3.3 3.3	3.0 3.0 3.0 4.5 3.0 4.5 3.0 4.5 3.3	0.2 0.4 0.8 0.77 0.85 0.8 60	0.2 0.4 0.8 0.77 0.95 0.9 60	- V	$I_{OL} = 4 \text{ mA}$ $I_{OL} = 14 \text{ mA}$ $I_{OL} = 14 \text{ mA}$ $I_{OL} = 84 \text{ mA}$
R _D	Level Output Voltage Maximum Output Impedance Minimum Output Impedance Maximum Pull-Up	B _n , Y _n B _n , Y _n PLH PLH B ₁ -B ₈ , Y ₉ -Y ₁₃ B ₁ -B ₈ , Y ₉ -Y ₁₃	3.0 3.0 3.0 3.0 3.0 3.3 3.3 3.3 3.3	3.0 3.0 4.5 3.0 4.5 3.3	0.4 0.8 0.77 0.85 0.8 60	0.4 0.8 0.77 0.95 0.9 60	- V	I _{OL} = 14 m/ I _{OL} = 14 m/ I _{OL} = 84 m/
R _D	Voltage Maximum Output Impedance Minimum Output Impedance Maximum Pull-Up	B _n , Y _n PLH PLH B ₁ -B ₈ , Y ₉ -Y ₁₃ B ₁ -B ₈ , Y ₉ -Y ₁₃	3.0 3.0 3.0 3.0 3.3 3.3 3.3 3.3	3.0 4.5 3.0 4.5 3.3	0.8 0.77 0.85 0.8 60	0.8 0.77 0.95 0.9 60	- V	$I_{OL} = 4 \text{ mA}$ $I_{OL} = 14 \text{ mA}$ $I_{OL} = 14 \text{ mA}$ $I_{OL} = 84 \text{ mA}$ $I_{OL} = 84 \text{ mA}$
R _D	Maximum Output Impedance Minimum Output Impedance Maximum Pull-Up	B _n , Y _n PLH PLH B ₁ -B ₈ , Y ₉ -Y ₁₃ B ₁ -B ₈ , Y ₉ -Y ₁₃	3.0 3.0 3.0 3.3 3.3 3.3 3.3	4.5 3.0 4.5 3.3	0.77 0.85 0.8 60	0.77 0.95 0.9 60	_ v	I _{OL} = 14 mA I _{OL} = 84 mA
R _P	Impedance Minimum Output Impedance Maximum Pull-Up	PLH PLH B ₁ -B ₈ , Y ₉ -Y ₁₃ B ₁ -B ₈ , Y ₉ -Y ₁₃	3.0 3.0 3.3 3.3 3.3	3.0 4.5 3.3	0.85 0.8 60	0.95 0.9 60		$I_{OL} = 84 \text{ mA}$
R _P	Impedance Minimum Output Impedance Maximum Pull-Up	PLH B ₁ -B ₈ , Y ₉ -Y ₁₃ B ₁ -B ₈ , Y ₉ -Y ₁₃	3.0 3.3 3.3 3.3 3.3	4.5 3.3	0.8	0.9 60	-	
R _P	Impedance Minimum Output Impedance Maximum Pull-Up	B ₁ -B ₈ , Y ₉ -Y ₁₃ B ₁ -B ₈ , Y ₉ -Y ₁₃	3.3 3.3 3.3	3.3	60	60		I _{OL} = 84 mA
R _P	Impedance Minimum Output Impedance Maximum Pull-Up	B ₁ -B ₈ , Y ₉ -Y ₁₃	3.3 3.3					
R _P	Minimum Output Impedance Maximum Pull-Up		3.3	5.0	55	55		(NI-1- E)(NI-
R _P	Impedance Maximum Pull-Up				00	35	0	(Note 5)(No
R _P	Maximum Pull-Up	B1-B0, Y0-Y40		3.3	30	30	Ω	
		B ₄ -B ₈ , Y ₀ -Y ₄₀	3.3	5.0	35	35		(Note 5)(No
	Resistance	1 - 1 - 07 - 9 - 13.	3.3	3.3	1650	1650	_	
		C ₁₄ -C ₁₇	3.3	5.0	1650	1650	Ω	
	Minimum Pull-Up	B ₁ -B ₈ , Y ₉ -Y ₁₃	3.3	3.3	1150	1150		
	Resistance	C ₁₄ -C ₁₇	3.3	5.0	1150	1150	Ω	
IIH	Maximum Input	A ₉ –A ₁₃ , PLH _{IN} ,	3.6	3.6	1.0	1.0		V _I = 3.6V
	Current in	HD, DIR, HLH _{IN}						
	HIGH State	C ₁₄ -C ₁₇	3.6	3.6	50.0	50.0	μA	V _I = 3.6V
		C ₁₄ -C ₁₇	3.6	5.5	100	100		V _I = 5.5V
Ι _{ΙL}	Maximum Input	A ₉ -A ₁₃ , PLH _{IN} ,	3.6	3.6	-1.0	-1.0	μA	$V_{I} = 0.0V$
	Current in	HD, DIR, HLH _{IN}						· ·
	LOW State	C ₁₄ -C ₁₇	3.6	3.6	-3.5	-3.5	mA	$V_{I} = 0.0V$
		C ₁₄ -C ₁₇	3.6	5.5	-5.0	-5.0		$V_{1} = 0.0V$
I _{OZH}	Maximum Output	A ₁ -A ₈	3.6	3.6	20	20	μA	$V_0 = 3.6V$
0211	Disable Current	B ₁ -B ₈	3.6	3.6	50	50		V _O = 3.6V
	(HIGH)	B ₁ -B ₈	3.6	5.5	100	100	μA	$V_0 = 5.5V$
	Maximum	A ₁ -A ₈	3.6	3.6	-20	-20	μA	$V_0 = 0.0V$
	Output Disable	B ₁ -B ₈	3.6	3.6	-3.5	-3.5	mA	.0
	Current (LOW)	B ₁ -B ₈	3.6	5.5	-5.0	-5.0	mA	
	Power Down	B ₁ -B ₈ , Y ₉ -Y ₁₃ ,	0.0	0.0	0.0	0.0		
011	Output Leakage	PLH	0.0	0.0	100	100	μA	$V_0 = 5.5V$
	Power Down			+				
011	Input Leakage	C ₁₄ –C ₁₇ , HLH _{IN}	0.0	0.0	100	100	μA	$V_{I} = 5.5V$
	Power Down						-	
011 100	Leakage to V _{CC}		0.0	0.0	250	250	μA	(Note 6)
	Power Down Leakage			+		+	1	+
011 1002	to V _{CC-Cable}		0.0	0.0	250	250	μA	(Note 6)

Note 5: Output impedance is measured with the output active LOW and active HIGH (HD = HIGH).

Note 6: Power-down leakage to V_{CC} or $V_{CC-Cable}$ is tested by simultaneously forcing all pins on the cable-side (B₁-B₈, Y₉-Y₁₃, PLH, C₁₄-C₁₇ and HLH_{IN}) to 5.5V and measuring the resulting I_{CC} or I_{CC-Cable}.

Note 7: This parameter is guaranteed but not tested, characterized only.

		$T_A = 0°C$	to +70°C	T _A = -40°0	C to +85°C		
Symbol		V _{CC} = 3.	0V–3.6V	V _{CC} = 3.	Units	Figure Number	
	Parameter	V _{CC—Cable} =	= 3.0V–5.5V	V _{CC—Cable}			
		Min	Max	Min	Max		
t _{PHL}	A ₁ -A ₈ to B ₁ -B ₈	2.0	40.0	2.0	44.0	ns	Figure 1
PLH	A ₁ -A ₈ to B ₁ -B ₈	2.0	40.0	2.0	44.0	ns	Figure 2
PHL	B ₁ -B ₈ to A ₁ -A ₈	2.0	40.0	2.0	44.0	ns	Figure 3
t _{PLH}	B ₁ -B ₈ to A ₁ -A ₈	2.0	40.0	2.0	44.0	ns	Figure 3
t _{PHL}	A ₉ -A ₁₃ to Y ₉ -Y ₁₃	2.0	40.0	2.0	44.0	ns	Figure 1
t _{PLH}	A ₉ -A ₁₃ to Y ₉ -Y ₁₃	2.0	40.0	2.0	44.0	ns	Figure 2
t _{PHL}	C ₁₄ -C ₁₇ to A ₁₄ -A ₁₇	2.0	40.0	2.0	44.0	ns	Figure 3
t _{PLH}	C ₁₄ -C ₁₇ to A ₁₄ -A ₁₇	2.0	40.0	2.0	44.0	ns	Figure 3
tSKEW	LH-LH or HL-HL		10.0		12.0	ns	(Note 9)
t _{PHL}	PLH _{IN} to PLH	2.0	40.0	2.0	44.0	ns	Figure 1
t _{PLH}	PLH _{IN} to PLH	2.0	40.0	2.0	44.0	ns	Figure 2
t _{PHL}	HLH _{IN} to HLH	2.0	40.0	2.0	44.0	ns	Figure 3
t _{PLH}	HLH _{IN} to HLH	2.0	40.0	2.0	44.0	ns	Figure 3
t _{PHZ}	Output Disable Time	2.0	15.0	2.0	18.0		Figure
t _{PLZ}	DIR to A1-A8	2.0	15.0	2.0	18.0	ns	
t _{PZH}	Output Enable Time	2.0	50.0	2.0	50.0		Einen (
t _{PZL}	DIR to A1-A8	2.0	50.0	2.0	50.0	ns	Figure 8
t _{PHZ}	Output Disable Time	2.0	50.0	2.0	50.0		Figure
t _{PLZ}	DIR to B ₁ -B ₈	2.0	50.0	2.0	50.0	ns	
t _{pEN}	Output Enable Time	2.0	25.0	2.0	28.0	ns	Figure 2
	HD to B ₁ -B ₈ , Y ₉ -Y ₁₃	2.0	25.0	2.0	28.0		
t _{pDIS}	Output Disable Time	2.0	25.0	2.0	28.0		Figure (
	HD to B1-B8, Y9-Y13	2.0	25.0	2.0	28.0	ns	Figure 2
t _{pEN} -t _{pDIS}	Output Enable-		10.0		12.0	ns	
	Output Disable						
t _{SLEW}	Output Slew Rate						1
t _{PLH}	B ₁ -B ₈ , Y ₉ -Y ₁₃	0.05	0.40	0.05	0.40	V/ns	Figure 5
t _{PHL}		0.05	0.40	0.05	0.40		Figure 4
t _r , t _f	t _{RISE} and t _{FALL}		120		120		Figure 6
	B ₁ -B ₈ (Note 8),		120		120	ns	(Note 10
	Y ₉ -Y ₁₃ (Note 8)						1

Note 8: Open Drain

Note 9: t_{SKEW} is measured for common edge output transitions and compares the measured propagation delay for a given path type:

(i) $\mathsf{A}_1\text{-}\mathsf{A}_8$ to $\mathsf{B}_1\text{-}\mathsf{B}_8,\,\mathsf{A}_9\text{-}\mathsf{A}_{13}$ to $\mathsf{Y}_9\text{-}\mathsf{Y}_{13}$

(ii) $B_1 - B_8$ to $A_1 - A_8$

(iii) C₁₄-C₁₇ to A₁₄-A₁₇

Note 10: This parameter is guaranteed but not tested, characterized only.

Capacitance

Symbol	Parameter	Тур	Units	Conditions			
C _{IN}	Input Capacitance	3	pF	$V_{CC} = 0.0V$ (HD, DIR, A ₉ –A ₁₃ , C ₁₄ –C ₁₇ , PLH _{IN} and HLH _{IN})			
C _{I/O} (Note 11)	I/O Pin Capacitance	5	pF	$V_{CC} = 3.3V$			

Note 11: $C_{I/O}$ is measured at frequency = 1 MHz, per MIL-STD-883B, Method 3012



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